

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S43	101	257/197.ccls. and ((back or backside) with (gate or electrode or conductor or contact))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 19:06
S44	63	257/565.ccls. and ((back or backside) with (electrode or gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/15 20:41
S45	207	(257/526).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/15 20:48
S46	5	(257/587 or 257/592).ccls. and (back near2 gate or backgate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/15 20:51
S47	38	(257/587 or 257/592).ccls. and (back near2 gate or backgate or back adj side or backside)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/15 20:51
S48	147	(257/E29.171,E29.183,E29.189,E29.19,E29.198).ccls. and ((back near4 (electrode or gate or conductor)) or backgate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/15 21:02
S49	203	semiconductor and (((back or buried) with (gate or electrode)) or backgate) and (inversion or accumulat\$5) and (vertical\$4 near5 bipolar)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/15 21:06